



## UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE  
 United States Patent and Trademark Office  
 Address: COMMISSIONER FOR PATENTS  
 P.O. Box 1450  
 Alexandria, Virginia 22313-1450  
 www.uspto.gov



Bib Data Sheet

CONFIRMATION NO. 8039

SERIAL NUMBER 10/645,805	FILING DATE 08/21/2003  RULE	CLASS 438	GROUP ART UNIT 2813	ATTORNEY DOCKET NO. 09792909-5657
-----------------------------	---------------------------------------	--------------	------------------------	---

## APPLICANTS

Dharam Pal Gosain, Tokyo, JAPAN;

Akio Machida, Kanagawa, JAPAN;

Kazushi Nakano, Tokyo, JAPAN; Toshio Fujino, Kanagawa, JAPAN;

Junichi Sato, Tokyo, JAPAN;

\*\* CONTINUING DATA \*\*\*\*\*

\*\* FOREIGN APPLICATIONS \*\*\*\*\*

JAPAN P2002-242614 08/22/2002

IF REQUIRED, FOREIGN FILING LICENSE GRANTED

\*\* 04/21/2004

Foreign Priority claimed <input checked="" type="checkbox"/> yes <input type="checkbox"/> no	STATE OR COUNTRY JAPAN	SHEETS DRAWING 17	TOTAL CLAIMS 37	INDEPENDENT CLAIMS 4
35 USC 119 (a-d) conditions met <input checked="" type="checkbox"/> yes <input type="checkbox"/> no <input type="checkbox"/> Met after Allowance				
Verified and Acknowledged Examiner's Signature	Initials			

## ADDRESS

26263

SONNENSCHN NATH &amp; ROSENTHAL LLP

P.O. BOX 061080

WACKER DRIVE STATION, SEARS TOWER

CHICAGO, IL

60606-1080

## TITLE

Method of producing crystalline semiconductor material and method of fabricating semiconductor device

FILING FEE	FEES: Authority has been given in Paper	<input type="checkbox"/> All Fees
		<input type="checkbox"/> 1.16 Fees ( Filing )
		<input type="checkbox"/> 1.17 Fees ( Processing Ext. of

RECEIVED 1270	No. _____ to charge/credit DEPOSIT ACCOUNT	time )
	No. _____ for following:	<input type="checkbox"/> 1.18 Fees ( Issue )
		<input type="checkbox"/> Other _____
		<input type="checkbox"/> Credit